

## Features

- High speed
  - $t_{AA} = 17 \text{ ns}$
- Low active power
  - 1073 mW (max.)
- Low CMOS standby power
  - 2.75 mW (max.)
- 2.0 V data retention (400  $\mu\text{W}$  at 2.0 V retention)
- Automatic power-down when deselected
- TTL-compatible inputs and outputs
- Easy memory expansion with CE and OE features

## Functional Description

The CY7C1049BN is a high-performance CMOS static RAM organized as 524,288 words by 8 bits. Easy memory expansion is provided by an active LOW Chip Enable ( $\overline{\text{CE}}$ ), an active LOW Output Enable ( $\overline{\text{OE}}$ ), and three-state drivers. Writing to the device is accomplished by taking Chip Enable ( $\overline{\text{CE}}$ ) and Write Enable ( $\overline{\text{WE}}$ ) inputs LOW. Data on the eight I/O pins ( $\text{I/O}_0$  through  $\text{I/O}_7$ ) is then written into the location specified on the address pins ( $\text{A}_0$  through  $\text{A}_{18}$ ).

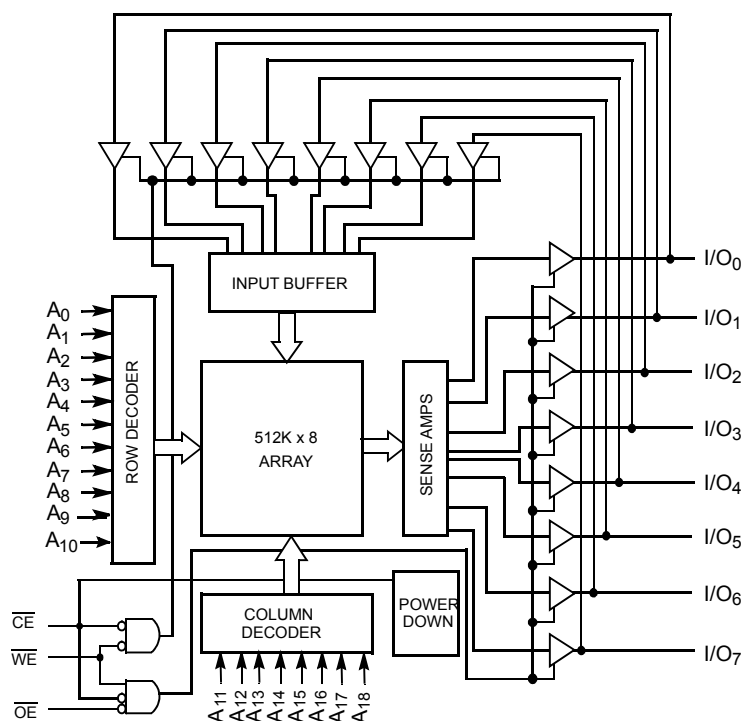
Reading from the device is accomplished by taking Chip Enable ( $\overline{\text{CE}}$ ) and Output Enable ( $\overline{\text{OE}}$ ) LOW while forcing Write Enable ( $\overline{\text{WE}}$ ) HIGH. Under these conditions, the contents of the memory location specified by the address pins will appear on the I/O pins.

The eight input/output pins ( $\text{I/O}_0$  through  $\text{I/O}_7$ ) are placed in a high-impedance state when the device is deselected ( $\overline{\text{CE}}$  HIGH), the outputs are disabled ( $\overline{\text{OE}}$  HIGH), or during a write operation ( $\overline{\text{CE}}$  LOW, and  $\overline{\text{WE}}$  LOW).

The CY7C1049BN is available in a standard 400-mil-wide 36-pin SOJ package with center power and ground (revolutionary) pinout.

For a complete list of related documentation, [click here](#).

## Logic Block Diagram

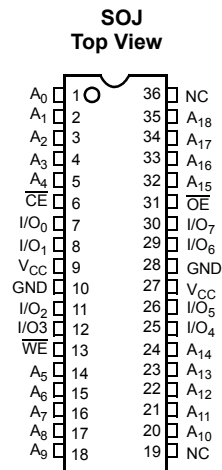


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## Pinouts

Figure 1. 36-pin SOJ pinout (Top View)



## Selection Guide

| Description                       | CY7C1049BNL-17 |
|-----------------------------------|----------------|
| Maximum Access Time (ns)          | 17             |
| Maximum Operating Current (mA)    | 195            |
| Maximum CMOS Standby Current (mA) | 0.5            |

## Maximum Ratings

Exceeding maximum ratings may shorten the useful life of the device. These user guidelines are not tested.

Storage Temperature ..... -65 °C to +150 °C

Ambient Temperature with  
Power Applied ..... -55 °C to +125 °C

Supply Voltage on  
 $V_{CC}$  to Relative GND <sup>[1]</sup> ..... -0.5 V to +7.0 V

DC Voltage Applied to Outputs  
in High Z State <sup>[1]</sup> ..... -0.5 V to  $V_{CC} + 0.5$  V

DC Input Voltage <sup>[1]</sup> ..... -0.5 V to  $V_{CC} + 0.5$  V

Current into Outputs (LOW) ..... 20 mA

Static Discharge Voltage  
(per MIL-STD-883, Method 3015) ..... >2001 V

Latch-Up Current ..... >200 mA

## Operating Range

| Range        | Ambient Temperature | $V_{CC}$    |
|--------------|---------------------|-------------|
| Commercial L | 0 °C to +70 °C      | 4.5 V–5.5 V |

## Electrical Characteristics

Over the Operating Range

| Parameter | Description                                      | Test Conditions                                                                                                                                            | 7C1049B-17 |                | Unit |
|-----------|--------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------|------------|----------------|------|
|           |                                                  |                                                                                                                                                            | Min        | Max            |      |
| $V_{OH}$  | Output HIGH Voltage                              | $V_{CC} = \text{Min.}, I_{OH} = -4.0 \text{ mA}$                                                                                                           | 2.4        | –              | V    |
| $V_{OL}$  | Output LOW Voltage                               | $V_{CC} = \text{Min.}, I_{OL} = 8.0 \text{ mA}$                                                                                                            | –          | 0.4            | V    |
| $V_{IH}$  | Input HIGH Voltage                               |                                                                                                                                                            | 2.2        | $V_{CC} + 0.3$ | V    |
| $V_{IL}$  | Input LOW Voltage <sup>[1]</sup>                 |                                                                                                                                                            | –0.3       | 0.3            | V    |
| $I_{IX}$  | Input Load Current                               | $\text{GND} \leq V_I \leq V_{CC}$                                                                                                                          | –1         | +1             | μA   |
| $I_{OZ}$  | Output Leakage Current                           | $\text{GND} \leq V_{OUT} \leq V_{CC}$ ,<br>Output Disabled                                                                                                 | –1         | +1             | μA   |
| $I_{CC}$  | $V_{CC}$ Operating Supply Current                | $V_{CC} = \text{Max.},$<br>$f = f_{\text{MAX}} = 1/t_{RC}$                                                                                                 | –          | 195            | mA   |
| $I_{SB1}$ | Automatic CE Power-Down<br>Current – TTL Inputs  | Max. $V_{CC}$ , $\overline{CE} \geq V_{IH}$ ,<br>$V_{IN} \geq V_{IH}$ or $V_{IN} \leq V_{IL}$ , $f = f_{\text{MAX}}$                                       | –          | 40             | mA   |
| $I_{SB2}$ | Automatic CE Power-Down<br>Current – CMOS Inputs | Max. $V_{CC}$ , $\overline{CE} \geq V_{CC} - 0.3\text{V}$ ,<br>$V_{IN} \geq V_{CC} - 0.3\text{V}$ or $V_{IN} \leq 0.3 \text{ V}$ , $f = 0$ ,<br>Commercial | –          | 0.5            | mA   |

### Note

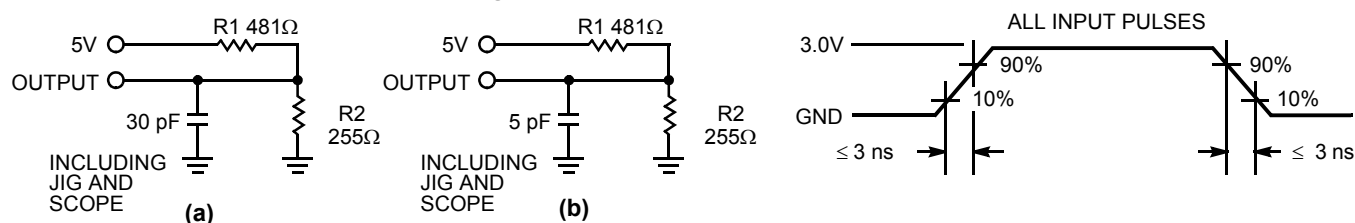
1. Minimum voltage is –2.0V for pulse durations of less than 20 ns.

## Capacitance

| Parameter <sup>[2]</sup> | Description       | Test Conditions                                                         | Max. | Unit |
|--------------------------|-------------------|-------------------------------------------------------------------------|------|------|
| $C_{IN}$                 | Input capacitance | $T_A = 25^\circ\text{C}$ , $f = 1\text{ MHz}$ , $V_{CC} = 5.0\text{ V}$ | 8    | pF   |
| $C_{OUT}$                | I/O capacitance   |                                                                         | 8    | pF   |

## AC Test Loads and Waveforms

Figure 2. AC Test Loads and Waveforms



Equivalent to: THÉVENIN EQUIVALENT  
 $167\Omega$   
 OUTPUT 1.73V

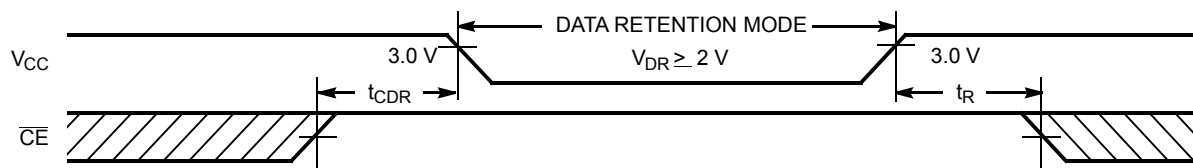
## Data Retention Characteristics

Over the Operating Range

| Parameter       | Description                          | Conditions <sup>[3]</sup> |   | Min      | Max | Unit          |
|-----------------|--------------------------------------|---------------------------|---|----------|-----|---------------|
| $V_{DR}$        | $V_{CC}$ for Data Retention          |                           |   | 2.0      | —   | V             |
| $I_{CCDR}$      | Data Retention Current               | Commercial                | L | —        | 200 | $\mu\text{A}$ |
| $t_{CDR}^{[2]}$ | Chip Deselect to Data Retention Time |                           |   |          |     |               |
| $t_R^{[4]}$     | Operation Recovery Time              |                           |   | $t_{RC}$ | —   | ns            |

## Data Retention Waveform

Figure 3. Data Retention Waveform



### Notes

- Tested initially and after any design or process changes that may affect these parameters.
- No input may exceed  $V_{CC} + 0.5\text{ V}$ .
- $t_r \leq 3\text{ ns}$  for the -12 and -15 speeds.  $t_r \leq 5\text{ ns}$  for the -20 and slower speeds.

## Switching Characteristics

Over the Operating Range

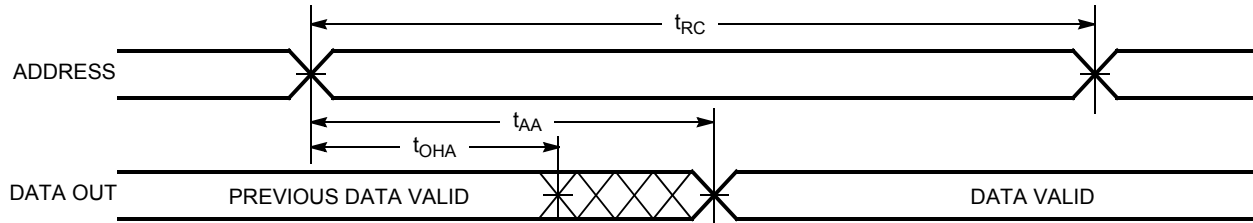
| Parameter <sup>[5]</sup>       | Description                                                  | CY7C1049BNL-17 |     | Unit |
|--------------------------------|--------------------------------------------------------------|----------------|-----|------|
|                                |                                                              | Min            | Max |      |
| Read Cycle                     |                                                              |                |     |      |
| t <sub>power</sub>             | V <sub>CC</sub> (typical) to the First Access <sup>[6]</sup> | 1              | –   | ms   |
| t <sub>RC</sub>                | Read Cycle Time                                              | 17             | –   | ns   |
| t <sub>AA</sub>                | Address to Data Valid                                        | –              | 17  | ns   |
| t <sub>OHA</sub>               | Data Hold from Address Change                                | 3              | –   | ns   |
| t <sub>ACE</sub>               | $\overline{\text{CE}}$ LOW to Data Valid                     | –              | 17  | ns   |
| t <sub>DOE</sub>               | $\overline{\text{OE}}$ LOW to Data Valid                     | –              | 8   | ns   |
| t <sub>LZOE</sub>              | $\overline{\text{OE}}$ LOW to Low Z <sup>[7]</sup>           | 0              | –   | ns   |
| t <sub>HZOE</sub>              | $\overline{\text{OE}}$ HIGH to High Z <sup>[7, 8]</sup>      | –              | 7   | ns   |
| t <sub>LZCE</sub>              | $\overline{\text{CE}}$ LOW to Low Z <sup>[7]</sup>           | 3              | –   | ns   |
| t <sub>HZCE</sub>              | $\overline{\text{CE}}$ HIGH to High Z <sup>[7, 8]</sup>      | –              | 7   | ns   |
| t <sub>PU</sub>                | $\overline{\text{CE}}$ LOW to Power-Up                       | 0              | –   | ns   |
| t <sub>PD</sub>                | $\overline{\text{CE}}$ HIGH to Power-Down                    | –              | 17  | ns   |
| Write Cycle <sup>[9, 10]</sup> |                                                              |                |     |      |
| t <sub>WC</sub>                | Write Cycle Time                                             | 17             | –   | ns   |
| t <sub>SCE</sub>               | $\overline{\text{CE}}$ LOW to Write End                      | 12             | –   | ns   |
| t <sub>AW</sub>                | Address Set-Up to Write End                                  | 12             | –   | ns   |
| t <sub>HA</sub>                | Address Hold from Write End                                  | 0              | –   | ns   |
| t <sub>SA</sub>                | Address Set-Up to Write Start                                | 0              | –   | ns   |
| t <sub>PWE</sub>               | $\overline{\text{WE}}$ Pulse Width                           | 12             | –   | ns   |
| t <sub>SD</sub>                | Data Set-Up to Write End                                     | 8              | –   | ns   |
| t <sub>HD</sub>                | Data Hold from Write End                                     | 0              | –   | ns   |
| t <sub>LZWE</sub>              | $\overline{\text{WE}}$ HIGH to Low Z <sup>[7]</sup>          | 3              | –   | ns   |
| t <sub>HZWE</sub>              | $\overline{\text{WE}}$ LOW to High Z <sup>[7, 8]</sup>       | –              | 8   | ns   |

### Notes

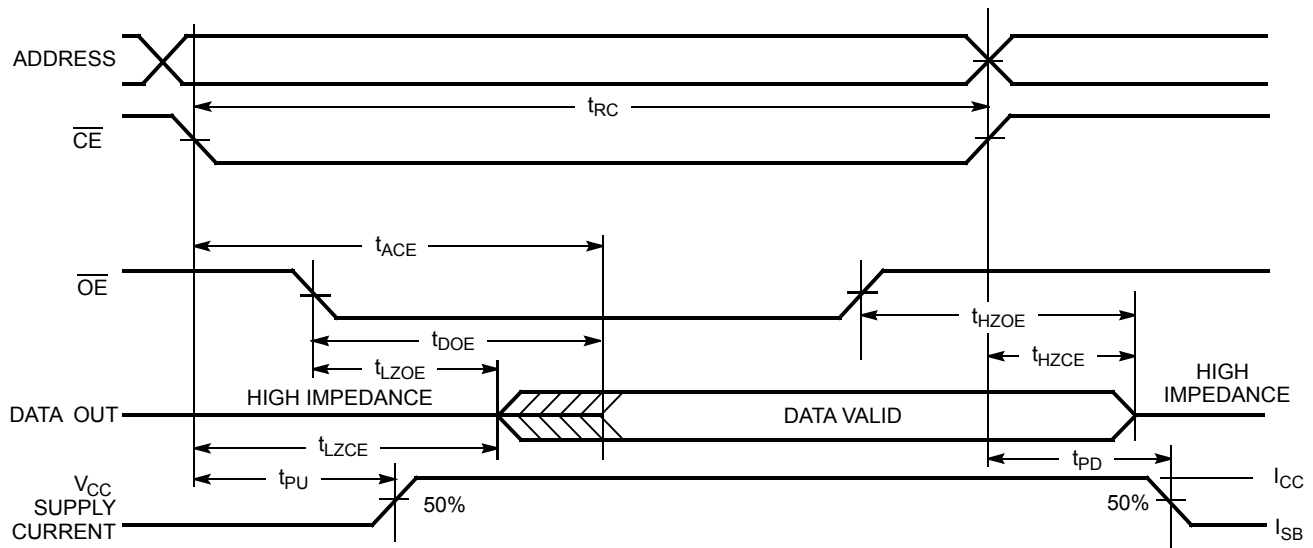
- Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V, and output loading of the specified  $I_{\text{OL}}/I_{\text{OH}}$  and 30-pF load capacitance.
- This part has a voltage regulator which steps down the voltage from 5V to 3.3V internally.  $t_{\text{power}}$  time has to be provided initially before a read/write operation is started.
- At any given temperature and voltage condition,  $t_{\text{HZCE}}$  is less than  $t_{\text{LZCE}}$ ,  $t_{\text{HZOE}}$  is less than  $t_{\text{LZOE}}$ , and  $t_{\text{HZWE}}$  is less than  $t_{\text{LZWE}}$  for any given device.
- $t_{\text{HZOE}}$ ,  $t_{\text{HZCE}}$ , and  $t_{\text{HZWE}}$  are specified with a load capacitance of 5 pF as in part (b) of AC Test Loads. Transition is measured  $\pm 500$  mV from steady-state voltage.
- The internal write time of the memory is defined by the overlap of  $\overline{\text{CE}}$  LOW, and  $\overline{\text{WE}}$  LOW.  $\overline{\text{CE}}$  and  $\overline{\text{WE}}$  must be LOW to initiate a write, and the transition of either of these signals can terminate the write. The input data set-up and hold timing should be referenced to the leading edge of the signal that terminates the write.
- The minimum write cycle time for Write Cycle No. 3 ( $\overline{\text{WE}}$  Controlled,  $\overline{\text{OE}}$  LOW) is the sum of  $t_{\text{HZWE}}$  and  $t_{\text{SD}}$ .

## Switching Waveforms

**Figure 4. Read Cycle No. 1** [11, 12]



**Figure 5. Read Cycle No. 2 ( $\overline{OE}$  Controlled)** [12, 13]



### Notes

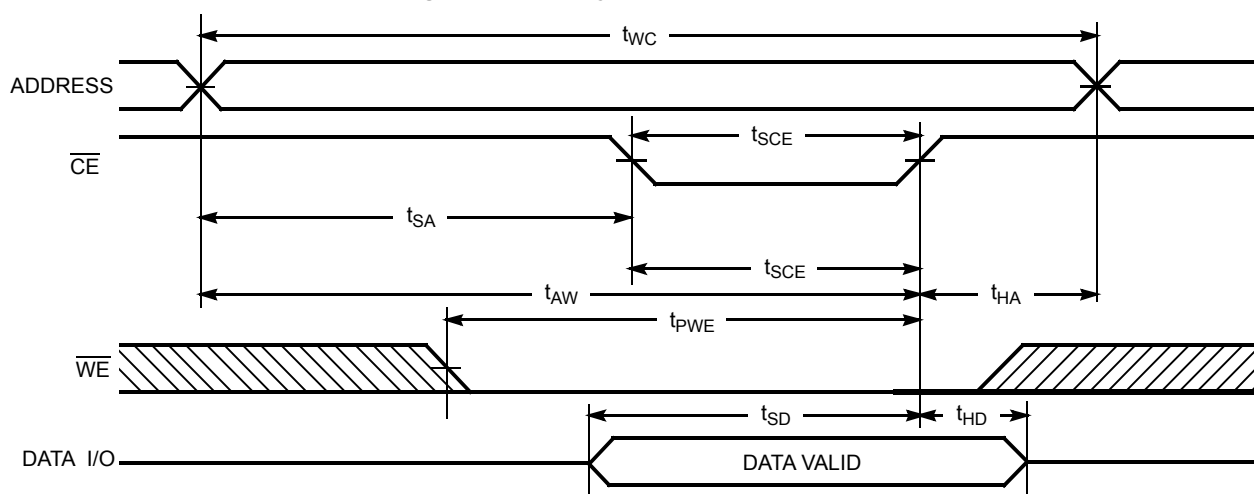
11. Device is continuously selected.  $\overline{OE}$ ,  $\overline{CE} = V_{IL}$ .

12.  $\overline{WE}$  is HIGH for read cycle.

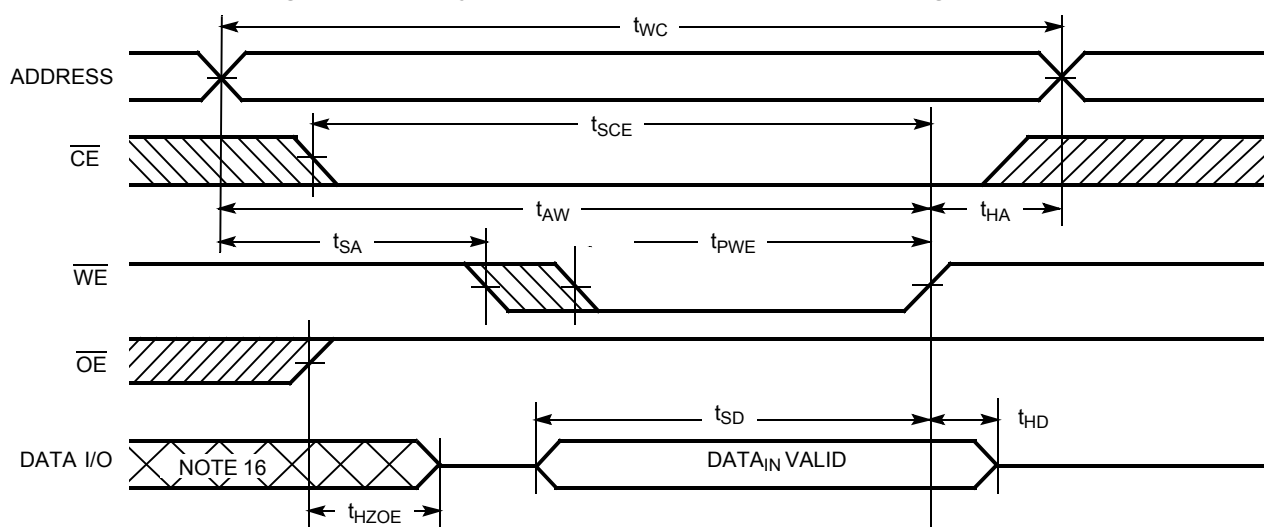
13. Address valid prior to or coincident with  $\overline{CE}$  transition LOW.

## Switching Waveforms (continued)

**Figure 6. Write Cycle No. 1 ( $\overline{\text{CE}}$  Controlled)** [14, 15]



**Figure 7. Write Cycle No. 2 ( $\overline{\text{WE}}$  Controlled,  $\overline{\text{OE}}$  HIGH during Write)** [14, 15]

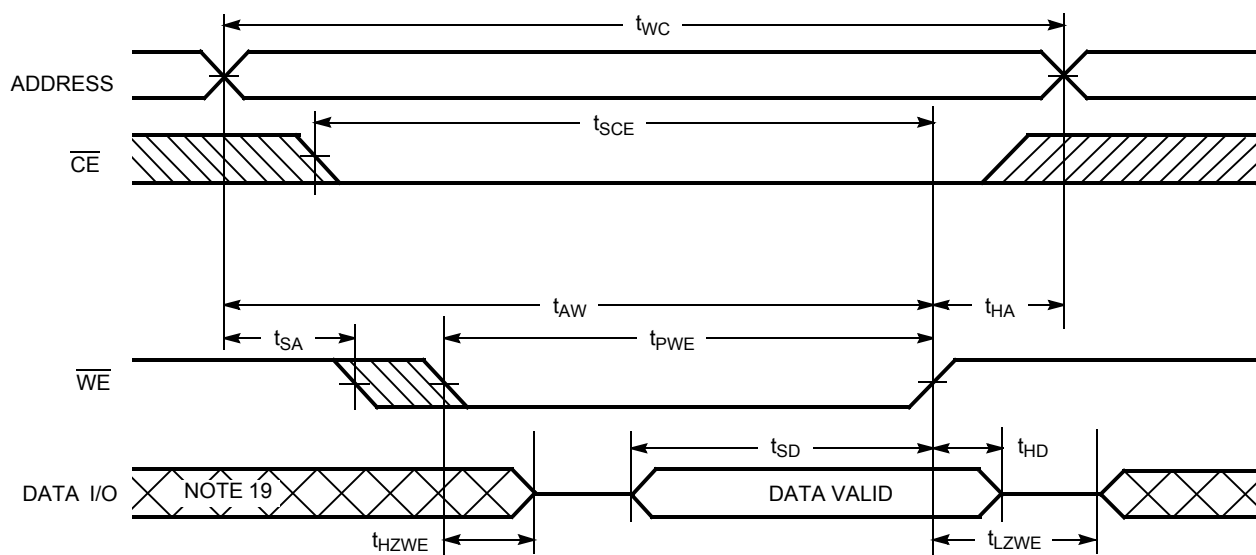


### Notes

14. Data I/O is high impedance if  $\overline{\text{OE}} = V_{IH}$ .
15. If  $\overline{\text{CE}}$  goes HIGH simultaneously with  $\overline{\text{WE}}$  going HIGH, the output remains in a high-impedance state.
16. During this period the I/Os are in the output state and input signals should not be applied.

## Switching Waveforms (continued)

Figure 8. Write Cycle No. 3 ( $\overline{WE}$  Controlled,  $\overline{OE}$  LOW) [17, 18]



### Notes

17. If  $\overline{CE}$  goes HIGH simultaneously with  $\overline{WE}$  going HIGH, the output remains in a high-impedance state.

18. The minimum write cycle pulse width should be equal to sum of  $t_{SD}$  and  $t_{HZWE}$ .

19. During this period the I/Os are in the output state and input signals should not be applied.

**Truth Table**

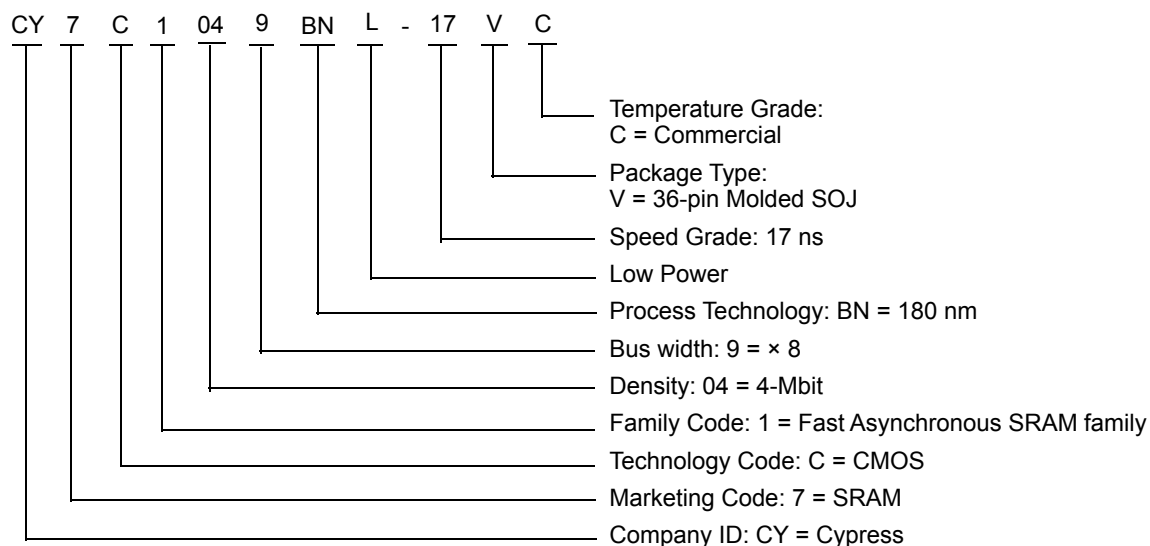
| $\overline{CE}$ | $\overline{WE}$ | $\overline{OE}$ | Inputs/Outputs | Mode                      | Power                |
|-----------------|-----------------|-----------------|----------------|---------------------------|----------------------|
| H               | X               | X               | High Z         | Power-down                | Standby ( $I_{SB}$ ) |
| L               | H               | L               | Data Out       | Read                      | Active ( $I_{CC}$ )  |
| L               | L               | X               | Data In        | Write                     | Active ( $I_{CC}$ )  |
| L               | H               | H               | High Z         | Selected, Output disabled | Active ( $I_{CC}$ )  |

## Ordering Information

The following table contains only the parts that are currently available. If you do not see what you are looking for, contact your local sales representative. For more information, visit the Cypress website at [www.cypress.com](http://www.cypress.com) and refer to the product summary page at <http://www.cypress.com/products>.

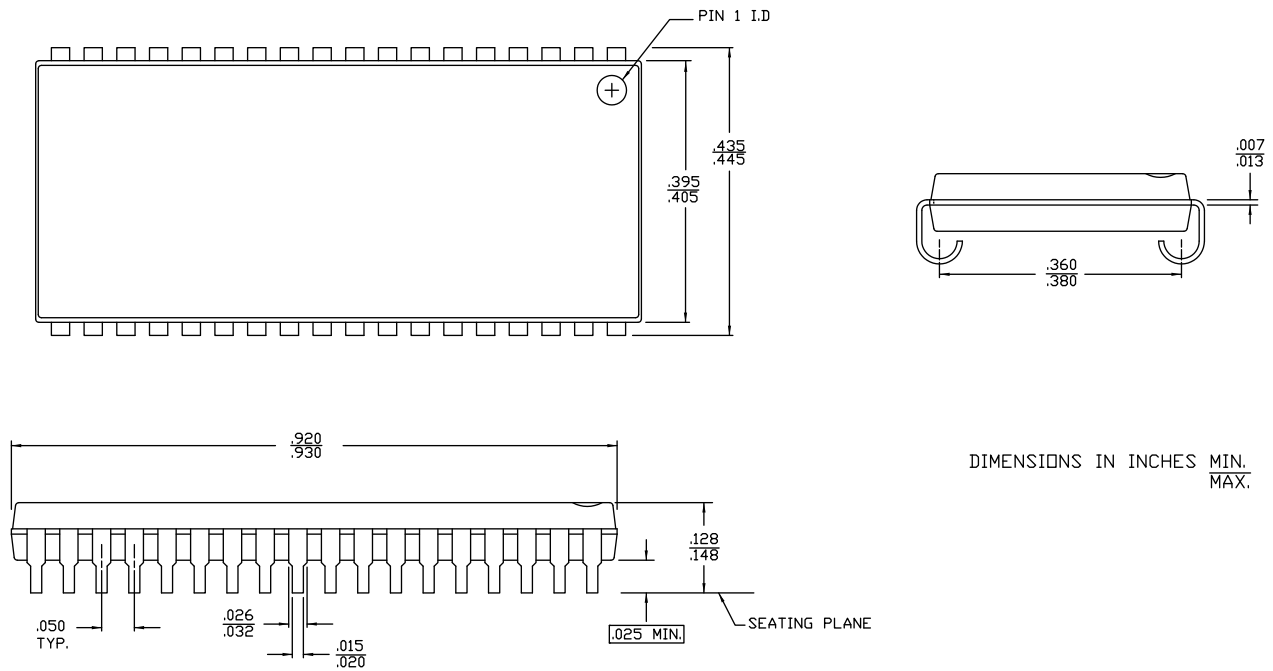
| Speed (ns) | Ordering Code    | Package Diagram | Package Type                | Operating Range |
|------------|------------------|-----------------|-----------------------------|-----------------|
| 17         | CY7C1049BNL-17VC | 51-85090        | 36-pin (400-Mil) Molded SOJ | Commercial      |

## Ordering Code Definitions



## Package Diagram

**Figure 9. 36-pin SOJ V36.4 (Molded) Package Outline, 51-85090**



51-85090 \*G

## Acronyms

| Acronym | Description                             |
|---------|-----------------------------------------|
| CE      | Chip Enable                             |
| CMOS    | Complementary Metal Oxide Semiconductor |
| I/O     | Input/Output                            |
| OE      | Output Enable                           |
| SRAM    | Static Random Access Memory             |
| WE      | Write Enable                            |

## Document Conventions

### Units of Measure

| Symbol | Unit of Measure |
|--------|-----------------|
| °C     | degree Celsius  |
| MHz    | megahertz       |
| μA     | microampere     |
| mA     | milliampere     |
| mV     | millivolt       |
| mW     | milliwatt       |
| ns     | nanosecond      |
| pF     | picofarad       |
| V      | volt            |
| W      | watt            |

## Document History Page

| Document Title: CY7C1049BN, 512 K × 8 Static RAM<br>Document Number: 001-76449 |         |                 |                 |                                                                                                                                                                                  |
|--------------------------------------------------------------------------------|---------|-----------------|-----------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Revision                                                                       | ECN     | Orig. of Change | Submission Date | Description of Change                                                                                                                                                            |
| **                                                                             | 3539227 | TAVA            | 03/01/2012      | New data sheet.                                                                                                                                                                  |
| *A                                                                             | 4371513 | VINI            | 05/06/2014      | Updated <a href="#">Switching Waveforms</a> :<br>Added Note 18 and referred the same note in <a href="#">Figure 8</a> .<br>Updated to new template.<br>Completing Sunset Review. |
| *B                                                                             | 4573121 | VINI            | 11/18/2014      | Updated <a href="#">Functional Description</a> :<br>Added "For a complete list of related documentation, <a href="#">click here</a> ." at the end.                               |
| *C                                                                             | 4765735 | VINI            | 05/14/2015      | Updated <a href="#">Package Diagram</a> :<br>spec 51-85090 – Changed revision from *F to *G.<br>Updated to new template.<br>Completing Sunset Review.                            |
| *D                                                                             | 6012105 | AESATP12        | 01/03/2018      | Updated logo and copyright.                                                                                                                                                      |

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